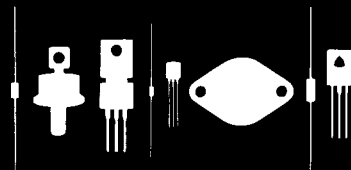


Central Semiconductor Corp.

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145 Adams Avenue  
 Hauppauge, New York 11788



2N3641 PN3641  
 2N3642 PN3642  
 2N3643 PN3643

JEDEC TO-105 JEDEC TO-92

NPN SILICON SIGNAL TRANSISTORS

DESCRIPTION

The CENTRAL SEMICONDUCTOR 2N3641, PN3641 Series types are Silicon NPN Small Signal Transistors designed for general purpose amplifier applications.

MAXIMUM RATINGS (T<sub>A</sub>=25°C)

	SYMBOL	2N3641 2N3643 PN3641 PN3643	2N3642 PN3642	UNIT
Collector-Base Voltage	V <sub>CB0</sub>	60	60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	30	45	V
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	5.0	V
Collector Current	I <sub>C</sub>	500	500	mA
		2N3641 2N3642 2N3643	PN3641 PN3642 PN4643	
Power Dissipation Operating and Storage Junction Temperature	P <sub>D</sub> T <sub>J</sub> , T <sub>stg</sub>	350 -55 TO +125	625 -55 TO +150	mW °C

ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C)

SYMBOL	TEST CONDITIONS	2N3641 PN3641		2N3642 PN3642		2N3643 PN3643		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
I <sub>CES</sub>	V <sub>CE</sub> =50V		50		50		50	nA
BV <sub>CB0</sub>	I <sub>C</sub> =10μA	60		60		60		V
BV <sub>CES</sub>	I <sub>C</sub> =10μA	60		60		60		V
BV <sub>CEO</sub>	I <sub>C</sub> =10mA	30		45		30		V
BV <sub>EBO</sub>	I <sub>E</sub> =10μA	5.0		5.0		5.0		V
V <sub>CE(SAT)</sub>	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA		0.22		0.22		0.22	V
h <sub>FE</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =150mA	40	120	40	120	100	300	
h <sub>FE</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =500mA	15		15		25		
f <sub>T</sub>	V <sub>CE</sub> =5.0V, I <sub>C</sub> =50mA, f=100MHz	150		150		250		MHz
C <sub>ob</sub>	V <sub>CB</sub> =10V, f=140kHz		8.0		8.0		8.0	pF
G <sub>pe</sub>	V <sub>CE</sub> =15V, R <sub>G</sub> =140Ω, R <sub>L</sub> =260Ω, f=30MHz, P <sub>IN</sub> =40mW	10		10		10		dB
η	V <sub>CE</sub> =15V, R <sub>G</sub> =140Ω, R <sub>L</sub> =260Ω, f=30MHz, P <sub>IN</sub> =40mW	60		60		60		%
t <sub>on</sub>	I <sub>C</sub> =300mA, I <sub>B1</sub> =30mA		60		60		60	ns
t <sub>off</sub>	I <sub>C</sub> =300mA, I <sub>B1</sub> =I <sub>B2</sub> =30mA		150		150		150	ns